DATA SHEET

74LVT323.3V Quad 2-input OR gate

Product specification

1996 Aug 28

IC24 Data Handbook





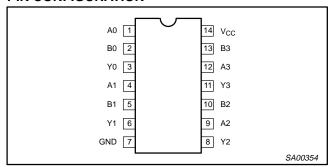


74LVT32

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An, Bn to Yn	$C_L = 50pF;$ $V_{CC} = 3.3V$	2.6 3.2	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	3	pF
I _{CCL}	Total supply current	Outputs Low; V _{CC} = 3.6V	1	mA

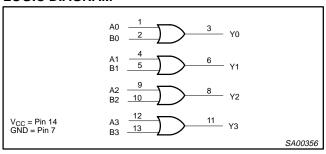
PIN CONFIGURATION



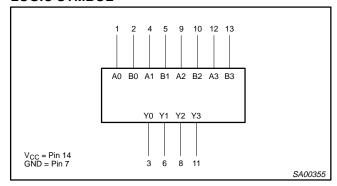
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn	Data inputs
3, 6, 8, 11	Yn	Data outputs
7	GND	Ground (0V)
14	V _{CC}	Positive supply voltage

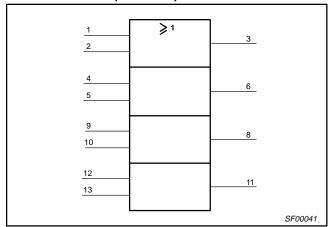
LOGIC DIAGRAM



LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INPL	JTS	OUTPUT
Dna	Dnb	Qn
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

NOTES:
H = High voltage level L = Low voltage level

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVT32 D	74LVT32 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT32 DB	74LVT32 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to +85°C	74LVT32 PW	74LVT32PW DH	SOT402-1

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3.3V Quad 2-input OR gate

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V _{CC}	DC supply voltage		-0.5 to +4.6	V	
I _{IK}	DC input diode current	V ₁ < 0	-50	mA	
VI	DC input voltage ³		-0.5 to +7.0	V	
lok	DC output diode current	V _O < 0	-50	mA	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V	
	DC output ourroat	Output in High state	-32	A	
Гоит	DC output current	Output in Low state	64	mA	
T _{stg}	Storage temperature range		-65 to 150	°C	

NOTES:

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STIMBOL	FARAWEIER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
loh	High-level output current		-20	mA
I _{OL}	Low-level output current		32	mA
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

74LVT32

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			ı			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = ·	+85°C	UNIT	
			MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6\text{V}; I_{OH} = -100\mu\text{A}$	V _{CC} -0.2			
V _{OH}	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -6mA$	2.4			V
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0			1
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.2	
V _{OL}	Low-level output voltage	$V_{CC} = 2.7V; I_{OL} = 24mA$			0.5	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.5	
1	Input lookage ourrent	$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$			10	
Ι _Ι	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}$		μΑ		
I _{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			±100	μΑ
Іссн	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_{I} = GND or V_{CC} , I_{O} = 0			0.02	mA
I _{CCL}	Quiosochi suppiy ourient	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or V_{CC} , I_{O} = 0		1	2	IIIA
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} –0.6V, Other inputs at V_{CC} or GND			0.2	μА
C _I	Input capacitance	V _I = 3V or 0		3		pF

NOTES:

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

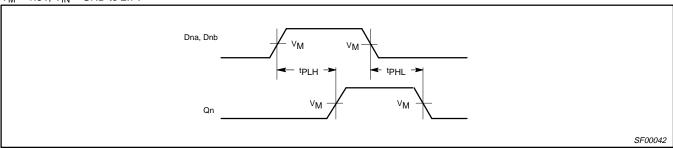
GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$, $R_L = 500 \Omega$; $T_{amb} = -40 ^{\circ} \text{C}$ to +85 $^{\circ} \text{C}$.

SYMBOL	PARAMETER	WAVEFORM	V _C	$_{2}$ = 3.3V \pm 0	V _{CC} = 2.7V	UNIT	
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An, Bn to Yn	1	1.0 1.0	2.6 3.2	3.8 4.6	4.5 4.9	ns

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

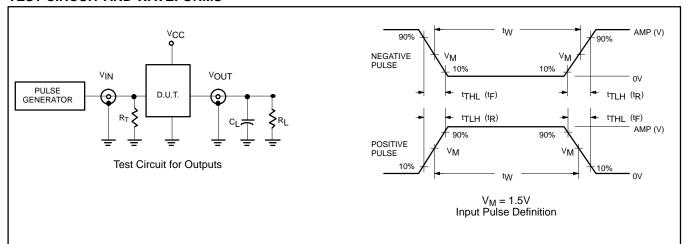
 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 2.7V$



Waveform 1. Propagation delay for inverting outputs

74LVT32

TEST CIRCUIT AND WAVEFORMS



DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

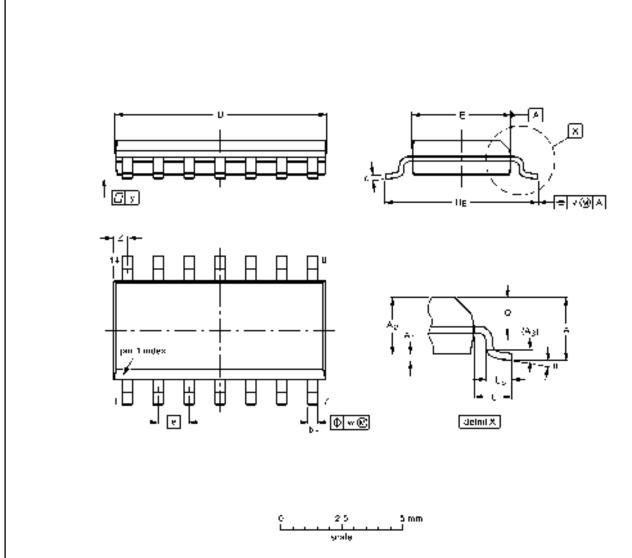
FAMILY	INPUT PULSE REQUIREMENTS											
	Amplitude	Rep. Rate	t _W	t _R	t _F							
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns							

SV00022

74LVT32

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (Inch dimensions are derived from the original men dimensions)

LHI IT	A max	4,	Az	43	PP	ė	$\boldsymbol{e}_{\Omega})$	€III	•	HE	١	Lp	Ģ	٧		ų	Z (0)	÷
mm	1.75	0. 25 0.10	145 125	0.25	0.45 0.00	0.25 0.19	B 75 8 55	4.0 3.0	1 27	52 58	116	1.0 U.A	0.7 0.6	0 25	0.25	01	07 03	B°
inches		00048 00039			0.018	0.0049 0.0075		0 16 0 15	0.050	023 023	0.041	0.000	0.028 0.024	001	0.01	0 004	0129 0012	05

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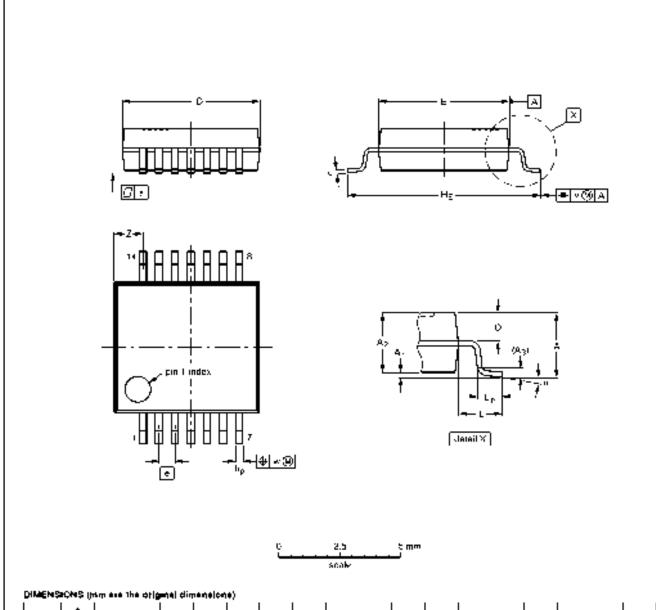
1. Health or metal profunctions of 0.15 mm more many particle are not included

OUTLINE		REFER	EUROPEAN	IBBUE DATE			
YERBION	IEC	1EDE¢	EITJ	PROJECTION	IBBUE DATE		
SOT108-1	076E06S	M5-012AB		\$	91 08 19 95-01-29		

74LVT32

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A mox.	Α,	A:	4,	Þр	£	Olul	€01	•	HE	L	Lp	à	¥	~	¥	201	1.
mm	20	0.21 0.05	180 165	0.20	0.08 0.25	0.20 0.09	67	4 :2 6 :3	0.65	70 76	125	1.03 0.63	0.9 0.7	0.2	0.10	9.1	14 09	O _D

Nou

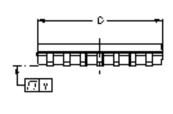
1. Plastic or metal profusions of 0.75 mm maximum per side are not included

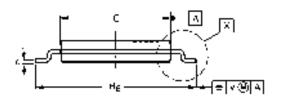
OUTLINE		REFER	EUROPEAN	IBBUE DATE	
VERBION	IEC	1EDE¢	EIT1	PROJECTION	IBBUE DATE
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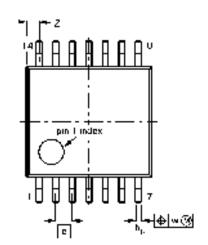
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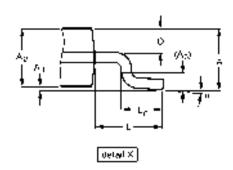
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

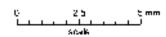
SOT402-1











DIMENSIONS (mm are the original dimensions)

UNIT	A X.Em	4,	Α2	4 3	b _P	٠	оm	€ 781	•	H _e	L	L _P	a	٧	₩	¥	Z (0)	"
mm	1 10	0.15 0.05	0.03 0.80	0.25	0.00 0.19	0 I	5.1 4.9	45 4,3	055	66 02	1.0	0.75 0.59	04	02	0 13	0.1	0.72 0.38	e° o°

Notes

- 1. Plastic or metal profiusions of 0.15 mm maximum per side are not included.
- 2. Plastic interload provisions of 0.25 mm maximum per side are not included

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
YERSION	IEC	JEDEC	EITÌ		PROJECTION	ISSUE DATE
SQT402-1		MO-150			€ ⊕	- 94 07 12 95-14-04

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NOTES

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DEFINITIONS					
Data Sheet Identification	Product Status	Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.			
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.			
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.			

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